# N-Channel Power MOSFET 1.8 $\Omega$ , 600 Volts

#### Features

- Low ON Resistance
- Low Gate Charge
- 100% Avalanche Tested
- These Devices are Pb-Free and are RoHS Compliant

#### Applications

- Adapter (Notebook, Printer, Gaming)
- LCD Panel Power
- Lighting Ballasts

### **ABSOLUTE MAXIMUM RATINGS** (T<sub>C</sub> = 25°C unless otherwise noted)

Rating	Symbol	NDF	NDD/NDP	Unit	
Drain-to-Source Voltage	V <sub>DSS</sub>	600 (Note 1)		V	
Continuous Drain Current	I <sub>D</sub>	4.0 (	Note 2)	А	
Continuous Drain Current T <sub>A</sub> = 100°C	Ι <sub>D</sub>	2.7 (Note 2)		A	
Pulsed Drain Current, V <sub>GS</sub> @ 10V	I <sub>DM</sub>	14 (	Note 2)	А	
Power Dissipation (Note 1)	PD	28	95	W	
Gate-to-Source Voltage	V <sub>GS</sub>	:	±30	V	
Single Pulse Avalanche Energy, L = 6.4 mH, $I_D$ = 4.0 A	E <sub>AS</sub>	51		mJ	
ESD (HBM) (JESD 22-114-B)	V <sub>esd</sub>	2500		V	
RMS Isolation Voltage (t = 0.3 sec., R.H. ≤ 30%, T <sub>A</sub> = 25°C) (Figure 13)	V <sub>ISO</sub>	4500	-	V	
Peak Diode Recovery	dv/dt	4.5 (Note 3)		V/ns	
Continuous Source Current (Body Diode)	I <sub>S</sub>	4.0		A	
Maximum Temperature for Soldering Leads, 0.063" (1.6 mm) from Case for 10 s Package Body for 10 s	T <sub>L</sub> T <sub>PKG</sub>	300 260		°C	
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub> –55 to 150		to 150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface mounted on FR4 board using 1" sq. pad size, 1 oz cu

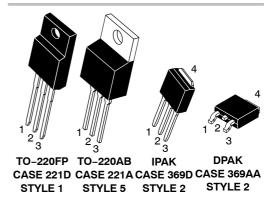
- 2. Limited by maximum junction temperature
- 3.  $I_{SD} = 4.0$  Å, di/dt  $\leq 100$  Å/µs,  $V_{DD} \leq BV_{DSS}$ ,  $T_J = +150^{\circ}C$

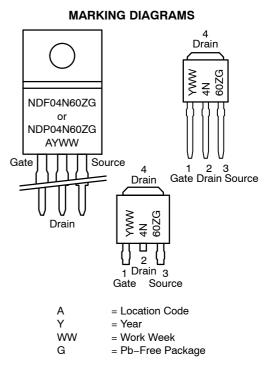


## **ON Semiconductor®**

#### http://onsemi.com

V <sub>DSS</sub>	R <sub>DS(ON)</sub> (TYP) @ 2 A
- 033	
600 V	1.8 Ω





#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### THERMAL RESISTANCE

Parameter	Symbol	NDF04N60Z	NDD/NDP	Unit
Junction-to-Case (Drain)		4.4	1.3	°C/W
Junction-to-Ambient Steady State (Note 4)		50	50	

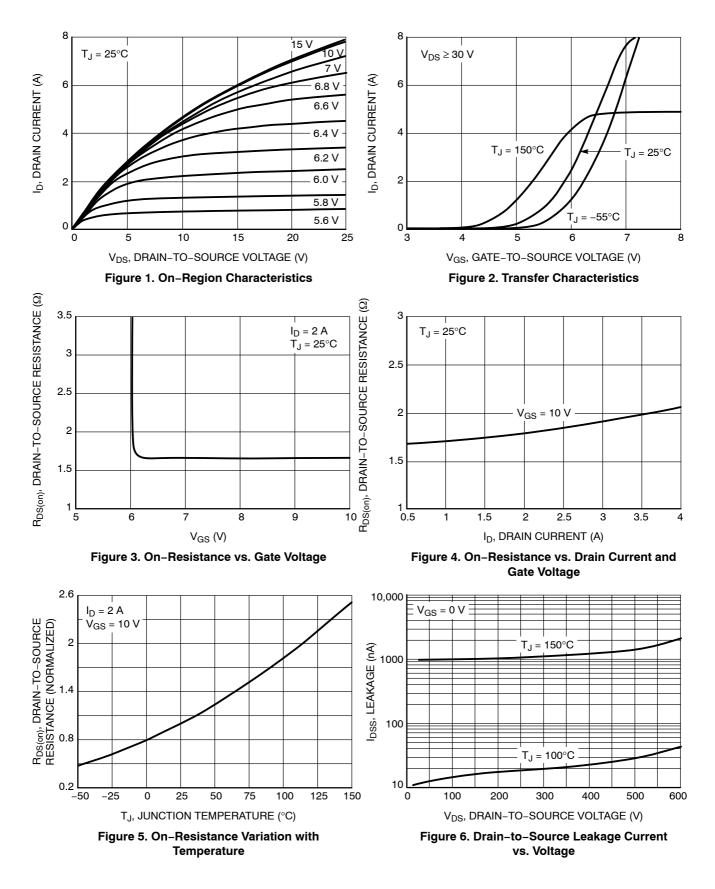
#### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted)

BV <sub>DS</sub> ΔBV <sub>D</sub> ΔΤ		 T	 T	
ΔBV <sub>D</sub>	50		T	
_	1			V
		0.6		V/°C
5°C I <sub>DS</sub>	S		1	μA
50°C			50	1
I <sub>GS</sub>	S		±10	μA
	-	-		-
R <sub>DS(0</sub>	on)	1.8	2.0	Ω
V <sub>GS(</sub>	<sub>th)</sub> 3.0		4.5	V
9FS	3	3.3		S
	-	-		-
Ciss	6	535		pF
Cos	s	62		
Crs	s	14		
Qg		19		nC
Qgs	3	3.9		1
Qgd	Ŀ	10		
Rg		4.7		Ω
	-	-		-
t <sub>d(or</sub>	ו)	13		ns
t <sub>r</sub>		9.0		1
t <sub>d(of</sub>	f)	24		1
t <sub>f</sub>		15		1
	IGSS RDS( VGS( 9FS Cos Cos Crs: Qg Qg Qg Qg Qg Cg td(or	$\begin{array}{c c} I_{GSS} \\ \hline R_{DS(on)} \\ \hline V_{GS(th)} & 3.0 \\ \hline g_{FS} \\ \hline C_{iss} \\ \hline C_{oss} \\ \hline C_{rss} \\ \hline C_{rss} \\ \hline Q_{g} \\ \hline Q_{gs} \\ \hline Q_{gd} \\ \hline R_{g} \\ \hline \end{array}$	$\begin{tabular}{ c c c c } \hline I_{GSS} & & & & & \\ \hline R_{DS(on)} & & 1.8 & & \\ \hline V_{GS(th)} & 3.0 & & & \\ \hline V_{GS(th)} & 3.0 & & & \\ \hline g_{FS} & 3.3 & & \\ \hline g_{FS} & 535 & & \\ \hline C_{oss} & 535 & & \\ \hline C_{oss} & 62 & & \\ \hline C_{rss} & 14 & & \\ \hline Q_g & 19 & & \\ \hline Q_{gs} & 3.9 & & \\ \hline Q_{gd} & 10 & & \\ \hline Q_{gd} & 10 & & \\ \hline R_g & 4.7 & & \\ \hline \hline t_{d(off)} & 13 & & \\ \hline t_{d(off)} & 24 & & \\ \hline \end{tabular}$	$\begin{array}{ c c c c c } I_{GSS} & & \pm 10 \\ \hline I_{GSS} & & \pm 10 \\ \hline R_{DS(on)} & 1.8 & 2.0 \\ \hline V_{GS(th)} & 3.0 & 4.5 \\ \hline 9_{FS} & 3.0 & 4.5 \\ \hline 9_{FS} & 3.3 & & \\ \hline \\ \hline \\ C_{iss} & 535 & & \\ \hline \\ C_{oss} & 62 & & \\ \hline \\ \hline \\ C_{rss} & 14 & & \\ \hline \\ C_{rss} & 14 & & \\ \hline \\ \hline \\ Q_{g} & 19 & & \\ \hline \\ Q_{gs} & 3.9 & & \\ \hline \\ Q_{gd} & 10 & & \\ \hline \\ R_{g} & 4.7 & & \\ \hline \\ \hline \\ \hline \\ t_{d(off)} & 13 & & \\ \hline \\ t_{d(off)} & 24 & & \\ \hline \\ t_{f} & 15 & & \\ \hline \end{array}$

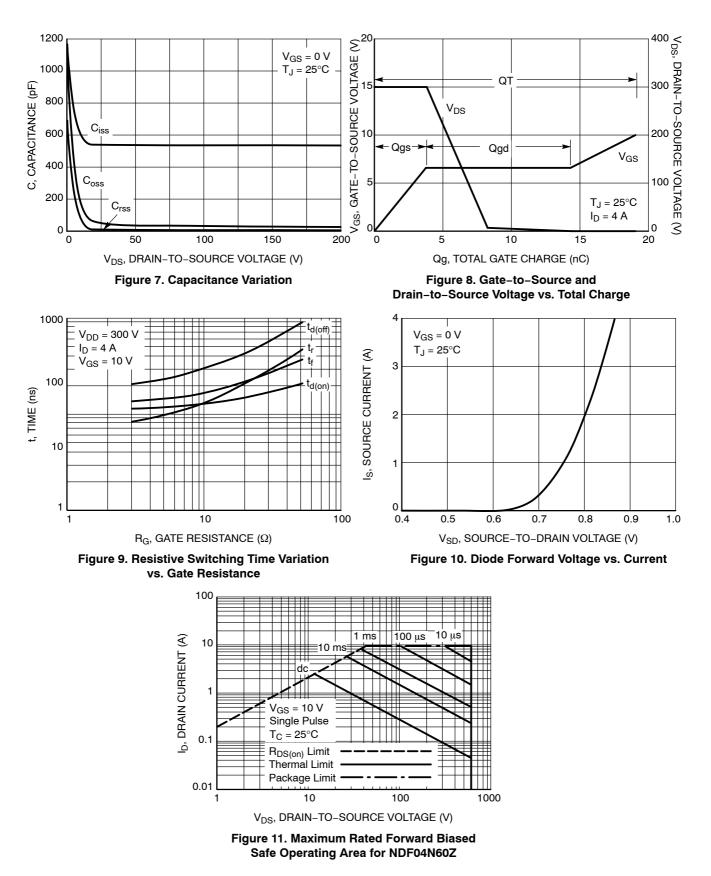
Diode Forward Voltage	$I_{S} = 4.0 \text{ A}, V_{GS} = 0 \text{ V}$	$V_{SD}$		1.6	V
Reverse Recovery Time	$V_{GS} = 0 V, V_{DD} = 30 V$	t <sub>rr</sub>	285		ns
Reverse Recovery Charge	$I_{S} = 4.0 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	Q <sub>rr</sub>	1.3		μC

4. Insertion mounted 5. Pulse Width  $\leq$  380  $\mu$ s, Duty Cycle  $\leq$  2%.

#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**



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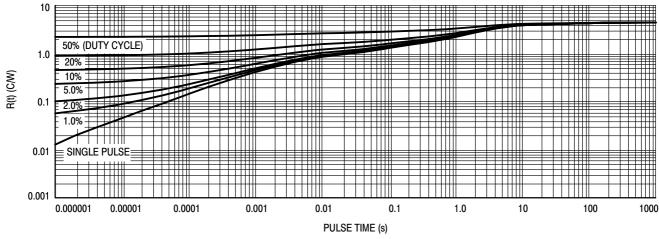
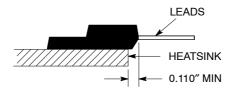


Figure 12. Thermal Impedance for NDF04N60Z

#### **ORDERING INFORMATION**

Order Number	Package	Shipping <sup>†</sup>
NDF04N60ZG	TO-220FP (Pb-Free)	50 Units / Rail
NDP04N60ZG	TO-220AB (Pb-Free)	In Development
NDD04N60Z-1G	IPAK (Pb-Free)	In Development
NDD04N60ZG	DPAK (Pb-Free)	In Development

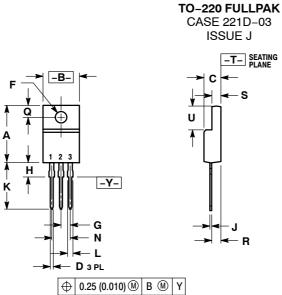
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.



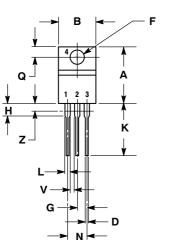


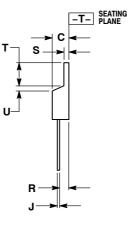
Measurement made between leads and heatsink with all leads shorted together.

#### PACKAGE DIMENSIONS



**TO-220AB** CASE 221A-09 **ISSUE AE** 





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH 3. 221D-01 THRU 221D-02 OBSOLETE, NEW STANDARD 221D-03.

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.617	0.635	15.67	16.12
В	0.392	0.419	9.96	10.63
С	0.177	0.193	4.50	4.90
D	0.024	0.039	0.60	1.00
F	0.116	0.129	2.95	3.28
G	0.100	BSC	2.54 BSC	
Η	0.118	0.135	3.00	3.43
-	0.018	0.025	0.45	0.63
K	0.503	0.541	12.78	13.73
L	0.048	0.058	1.23	1.47
Ν	0.200 BSC		5.08	BSC
Ø	0.122	0.138	3.10	3.50
R	0.099	0.117	2.51	2.96
s	0.092	0.113	2.34	2.87
C	0.239	0.271	6.06	6.88

STYLE 1: PIN 1. GATE

2. DRAIN 3. SOURCE

NOTES:

IDIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

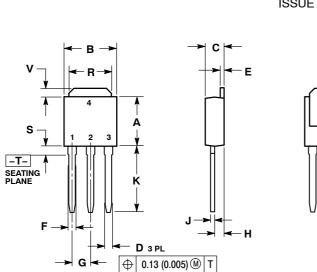
	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.161	3.61	4.09
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04

STYLE 5:

PIN 1. GATE 2. DRAIN

2. 3. SOURCE 4. DRAIN

## PACKAGE DIMENSIONS



IPAK CASE 369D-01 ISSUE B

¥

z

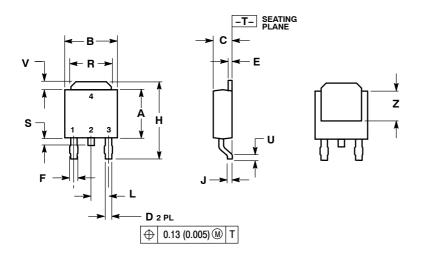
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090	BSC	2.29 BSC	
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
κ	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
۷	0.035	0.050	0.89	1.27
Ζ	0.155		3.93	

STYLE 2: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN

#### PACKAGE DIMENSIONS

DPAK CASE 369AA-01 ISSUE A



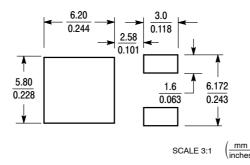
NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIM	IETERS		
DIM	MIN	MAX	MIN	MAX		
Α	0.235	0.245	5.97	6.22		
В	0.250	0.265	6.35	6.73		
С	0.086	0.094	2.19	2.38		
D	0.025	0.035	0.63	0.89		
Е	0.018	0.024	0.46	0.61		
F	0.030	0.045	0.77	1.14		
н	0.386	0.410	9.80	10.40		
J	0.018	0.023	0.46	0.58		
L	0.090	BSC	2.29	BSC		
R	0.180	0.215	4.57	5.45		
S	0.024	0.040	0.60	1.01		
U	0.020		0.51			
V	0.035	0.050	0.89	1.27		
Z	0.155		3.93			

STYLE 2: PIN 1. GATE 2. DRAIN

2. DRAIN 3. SOURCE 4. DRAIN

#### SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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